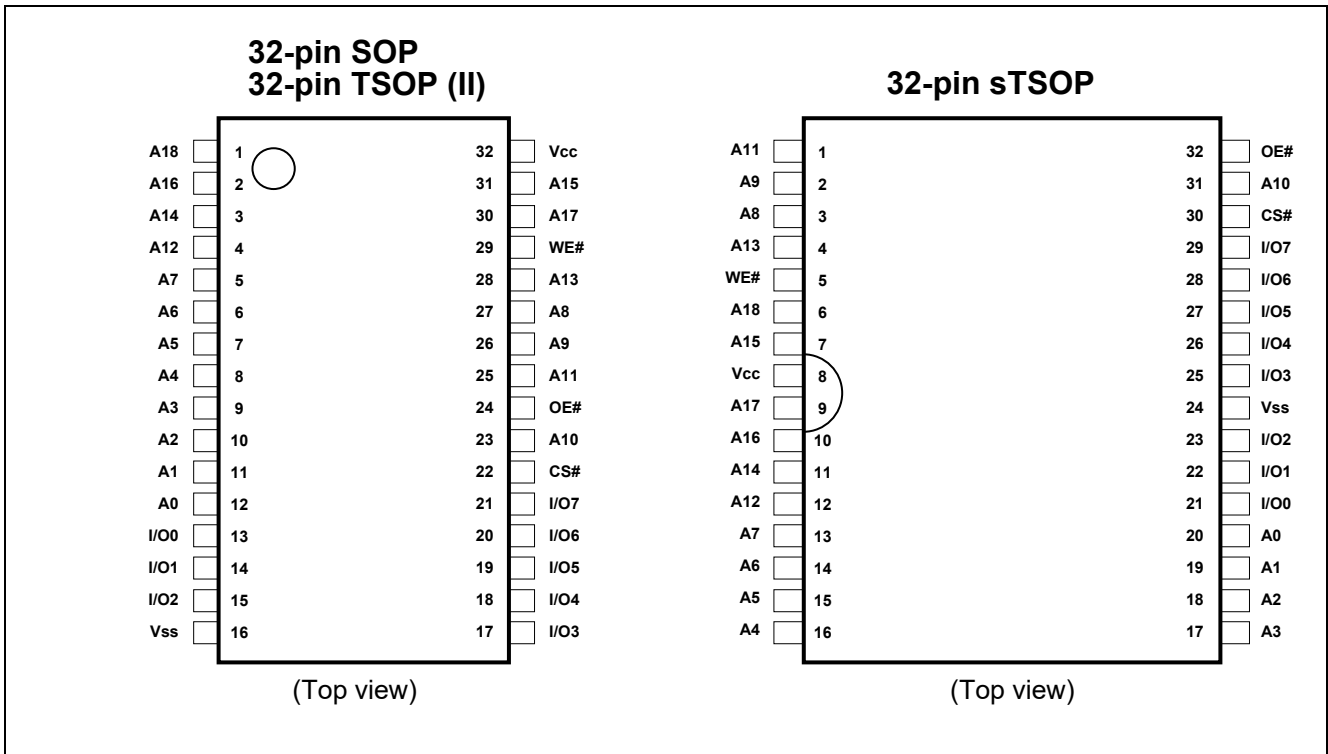


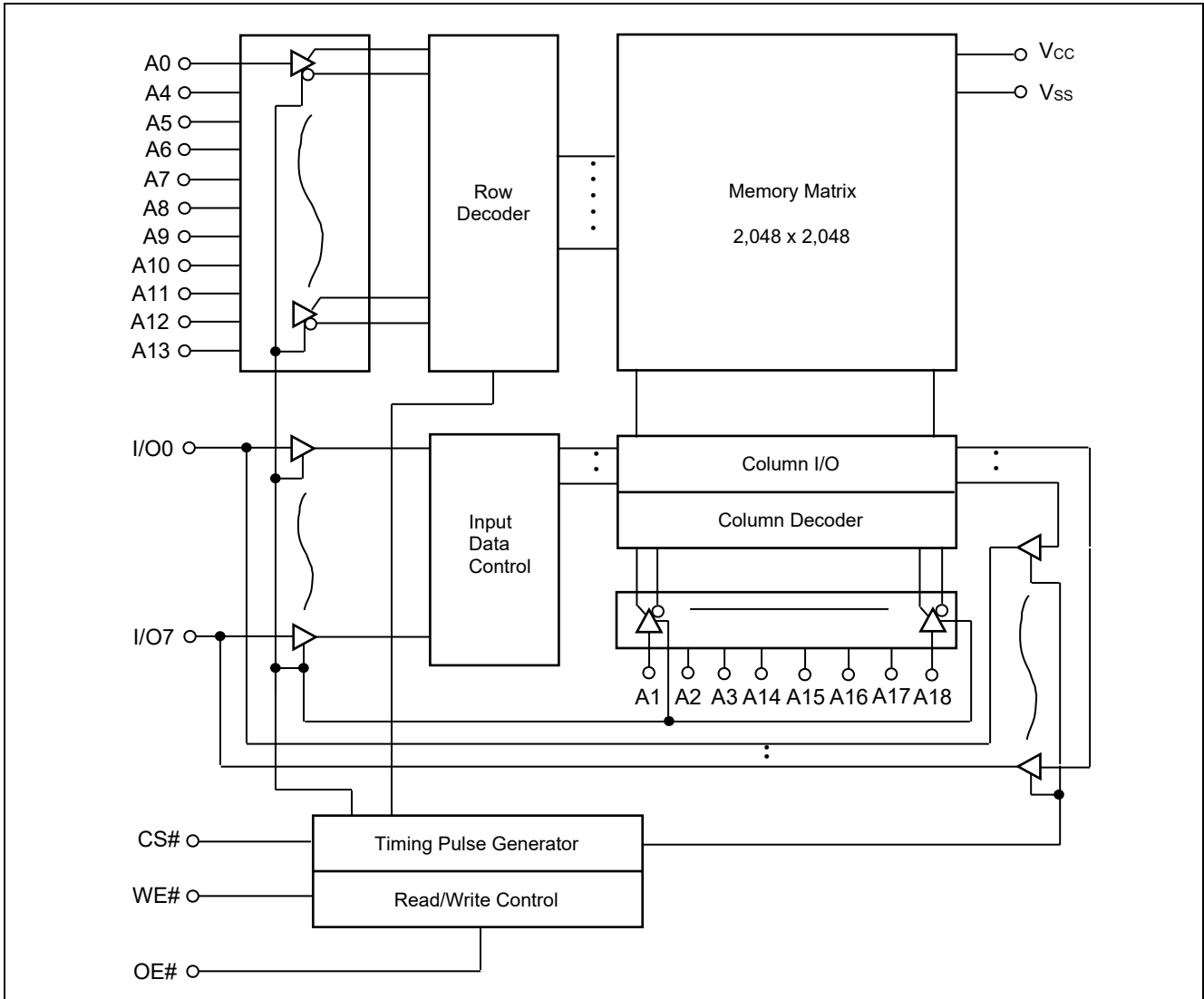
Pin Arrangement



Pin Description

Pin name	Function
Vcc	Power supply
Vss	Ground
A0 to A18	Address input
I/O0 to I/O7	Data input/output
CS#	Chip select
WE#	Write enable
OE#	Output enable

Block Diagram



Operation Table

CS#	WE#	OE#	I/O0 to I/O7	Operation
H	X	X	High-Z	Standby
L	H	L	Dout	Read
L	L	X	Din	Write
L	H	H	High-Z	Output disable

Note 2. H: V_{IH} L: V_{IL} X: V_{IH} or V_{IL}

Absolute Maximum Ratings

Parameter	Symbol	Value	unit
Power supply voltage relative to V_{SS}	V_{CC}	-0.5 to +4.6	V
Terminal voltage on any pin relative to V_{SS}	V_T	-0.5 ³ to $V_{CC}+0.3$ ⁴	V
Power dissipation	P_T	0.7	W
Operation temperature	T_{opr}	-40 to +85	°C
Storage temperature range	T_{stg}	-65 to +150	°C
Storage temperature range under bias	T_{bias}	-40 to +85	°C

Note 3. -3.0V for pulse ≤ 30 ns (full width at half maximum)

4. Maximum voltage is +4.6V.

DC Operating Conditions

Parameter	Symbol	Min.	Typ.	Max.	Unit	Note
Supply voltage	V_{CC}	2.7	3.0	3.6	V	
	V_{SS}	0	0	0	V	
Input high voltage	V_{IH}	2.2	—	$V_{CC}+0.3$	V	
Input low voltage	V_{IL}	-0.3	—	0.6	V	5
Ambient temperature range	T_a	-40	—	+85	°C	

Note 5. -3.0V for pulse ≤ 30 ns (full width at half maximum)

DC Characteristics

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test conditions	
Input leakage current	$ I_{LI} $	—	—	1	μ A	$V_{in} = V_{SS}$ to V_{CC}	
Output leakage current	$ I_{LO} $	—	—	1	μ A	$CS\# = V_{IH}$ or $OE\# = V_{IH}$ or $WE\# = V_{IL}$, $V_{I/O} = V_{SS}$ to V_{CC}	
Operating current	I_{CC}	—	—	10	mA	$CS\# = V_{IL}$, Others = V_{IH}/V_{IL} , $I_{I/O} = 0$ mA	
Average operating current	I_{CC1}	—	—	20	mA	Cycle = 55ns, duty = 100%, $I_{I/O} = 0$ mA, $CS\# = V_{IL}$, Others = V_{IH}/V_{IL}	
		—	—	25	mA	Cycle = 45ns, duty = 100%, $I_{I/O} = 0$ mA, $CS\# = V_{IL}$, Others = V_{IH}/V_{IL}	
	I_{CC2}	—	—	2.5	mA	Cycle = 1 μ s, duty = 100%, $I_{I/O} = 0$ mA, $CS\# \leq 0.2$ V, $V_{IH} \geq V_{CC}-0.2$ V, $V_{IL} \leq 0.2$ V	
Standby current	I_{SB}	—	0.1 ^{*6}	0.3	mA	$CS\# = V_{IH}$, Others = V_{SS} to V_{CC}	
Standby current	I_{SB1}	—	0.3 ^{*6}	2	μ A	~+25°C	$V_{in} = V_{SS}$ to V_{CC} , $CS\# \geq V_{CC}-0.2$ V
		—	—	3	μ A	~+40°C	
		—	—	5	μ A	~+70°C	
		—	—	7	μ A	~+85°C	
Output high voltage	V_{OH}	2.4	—	—	V	$I_{OH} = -1$ mA	
	V_{OH2}	$V_{CC}-0.2$	—	—	V	$I_{OH} = -0.1$ mA	
Output low voltage	V_{OL}	—	—	0.4	V	$I_{OL} = 2.1$ mA	
	V_{OL2}	—	—	0.2	V	$I_{OL} = 0.1$ mA	

Note 6. Typical parameter indicates the value for the center of distribution at 3.0V ($T_a = 25^\circ\text{C}$), and not 100% tested.

Capacitance

($V_{CC} = 2.7\text{V} \sim 3.6\text{V}$, $f = 1\text{MHz}$, $T_a = -40 \sim +85^\circ\text{C}$)

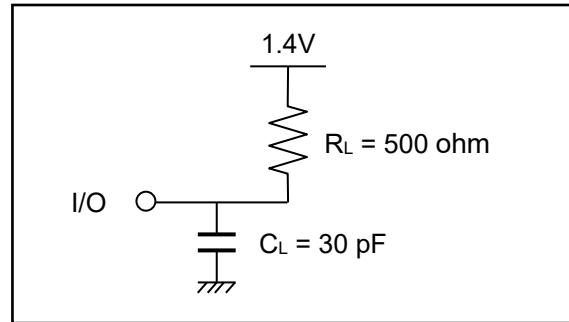
Parameter	Symbol	Min.	Typ.	Max.	Unit	Test conditions	Note
Input capacitance	C_{in}	—	—	8	pF	$V_{in} = 0$ V	7
Input / output capacitance	$C_{I/O}$	—	—	10	pF	$V_{I/O} = 0$ V	7

Note 7. This parameter is sampled and not 100% tested.

AC Characteristics

Test Conditions ($V_{CC} = 2.7V \sim 3.6V$, $T_a = -40 \sim +85^{\circ}C$)

- Input pulse levels: $V_{IL} = 0.4V$, $V_{IH} = 2.4V$
- Input rise and fall time: 5ns
- Input and output timing reference level: 1.4V
- Output load: See figures (Including scope and jig)



Read Cycle

Parameter	Symbol	Min.	Max.	Unit	Note
Read cycle time	t_{RC}	45	—	ns	
Address access time	t_{AA}	—	45	ns	
Chip select access time	t_{ACS}	—	45	ns	
Output enable to output valid	t_{OE}	—	22	ns	
Output hold from address change	t_{OH}	10	—	ns	
Chip select to output in low-Z	t_{CLZ}	10	—	ns	8,9
Output enable to output in low-Z	t_{OLZ}	5	—	ns	8,9
Chip deselect to output in high-Z	t_{CHZ}	0	18	ns	8,9,10
Output disable to output in high-Z	t_{OHZ}	0	18	ns	8,9,10

Write Cycle

Parameter	Symbol	Min.	Max.	Unit	Note
Write cycle time	t_{WC}	45	—	ns	
Address valid to write end	t_{AW}	35	—	ns	
Chip select to write end	t_{CW}	35	—	ns	
Write pulse width	t_{WP}	35	—	ns	11
Address setup time to write start	t_{AS}	0	—	ns	
Write recovery time from write end	t_{WR}	0	—	ns	
Data to write time overlap	t_{DW}	25	—	ns	
Data hold from write end	t_{DH}	0	—	ns	
Output enable from write end	t_{OW}	5	—	ns	8
Output disable to output in high-Z	t_{OHZ}	0	18	ns	8,10
Write to output in high-Z	t_{WHZ}	0	18	ns	8,10

Note 8. This parameter is sampled and not 100% tested.

9. At any given temperature and voltage condition, t_{CHZ} max is less than t_{CLZ} min, and t_{OHZ} max is less than t_{OLZ} min, for any device.

10. t_{CHZ} , t_{OHZ} and t_{WHZ} are defined as the time when the I/O pins enter a high-impedance state and are not referred to the I/O levels.

11. t_{WP} is the interval between write start and write end.

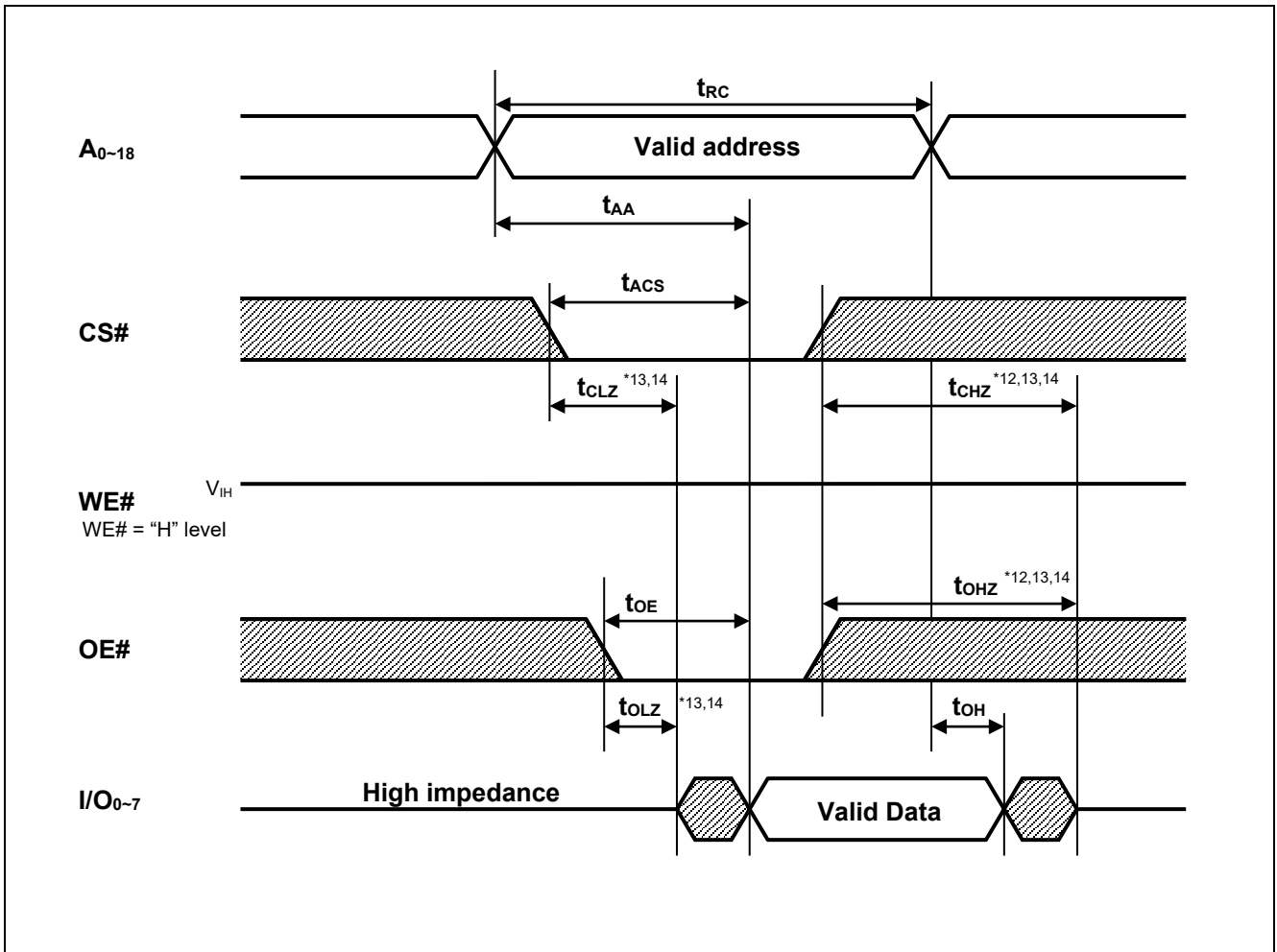
A write starts when both of CS# and WE# become active

A write is performed during the overlap of a low CS#, a low WE#

A write ends when any of CS#, WE# becomes inactive.

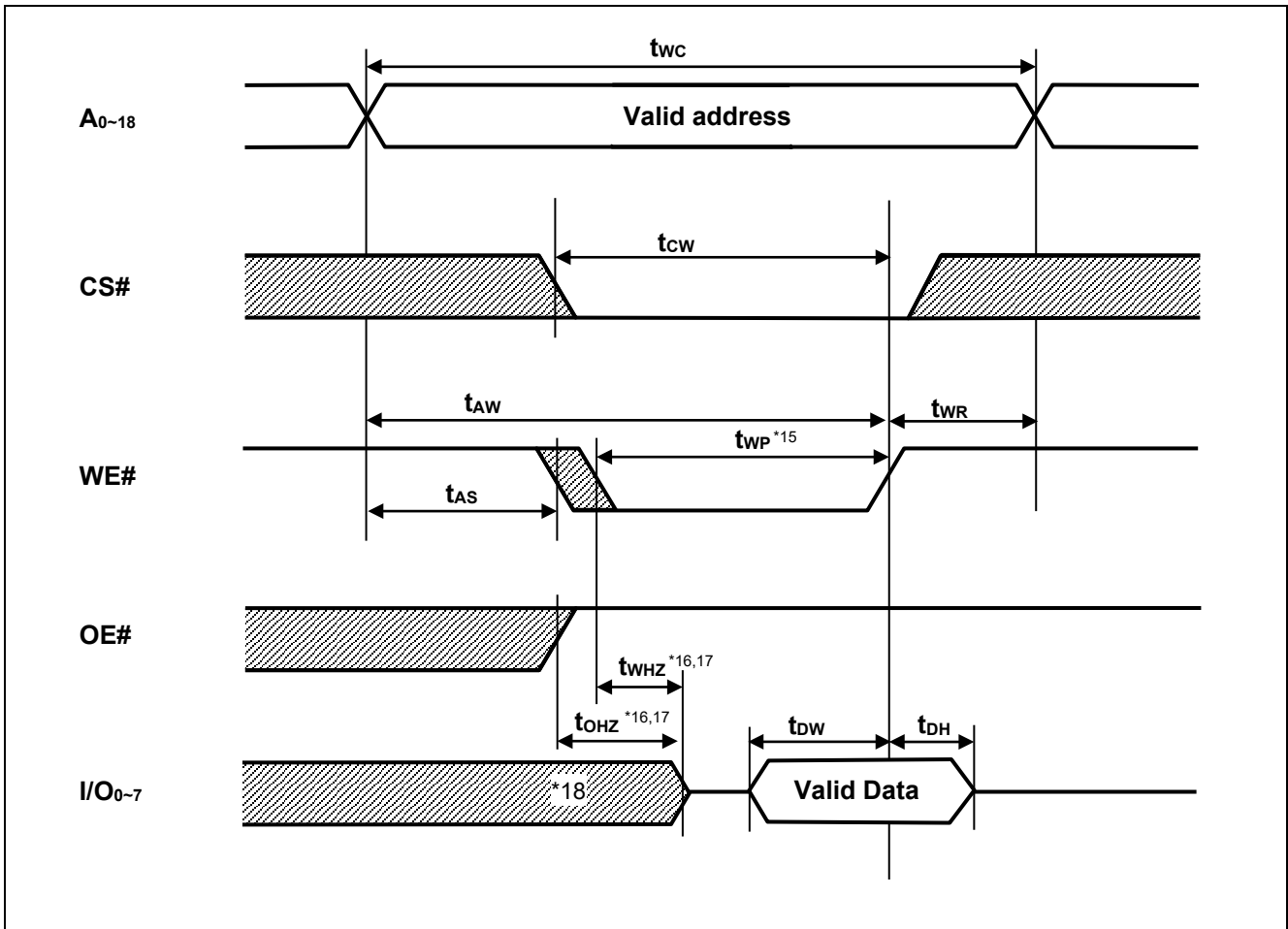
Timing Waveforms

Read Cycle



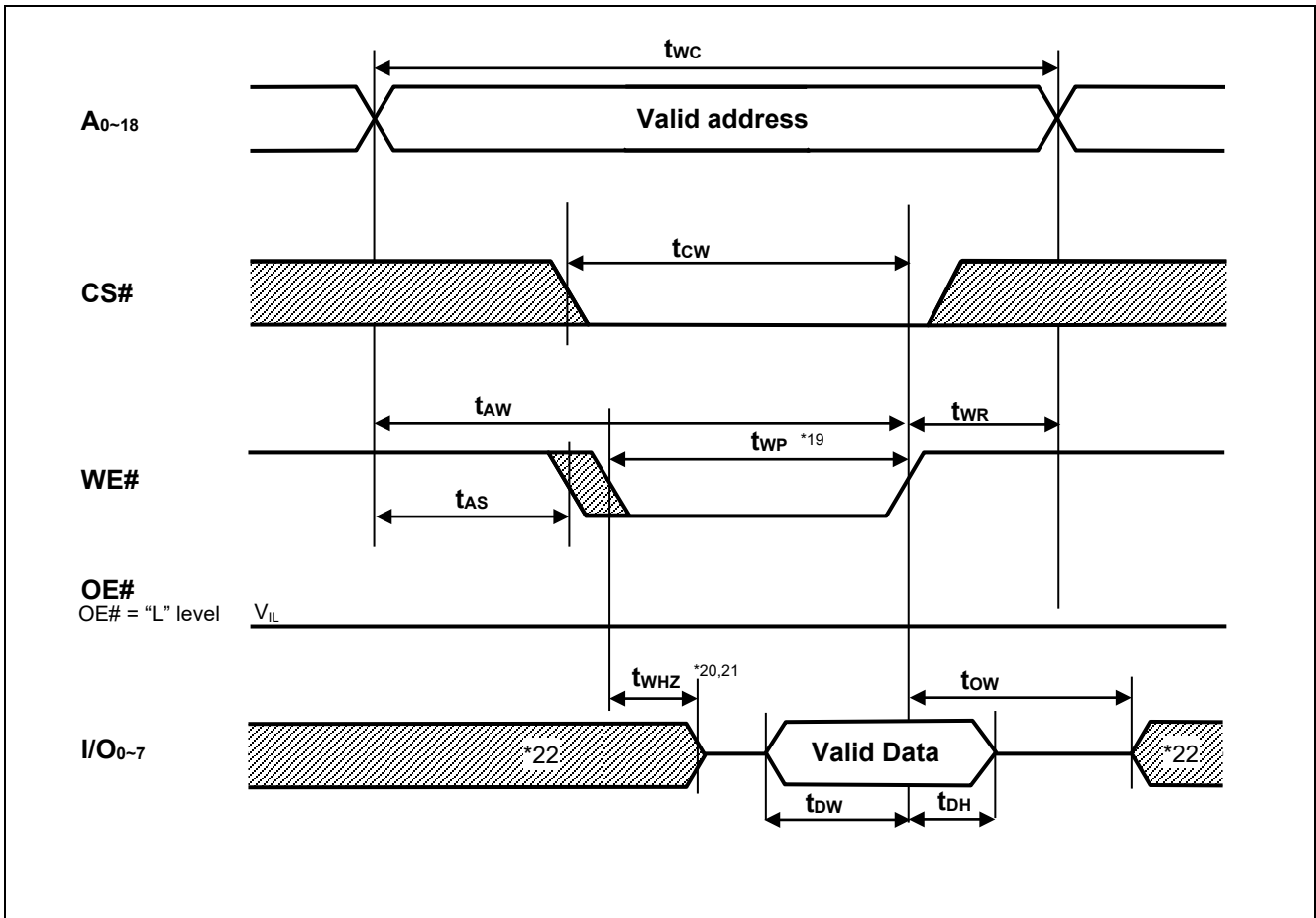
- Note 12. t_{CHZ} and t_{OHZ} are defined as the time when the I/O pins enter a high-impedance state and are not referred to the I/O levels.
13. This parameter is sampled and not 100% tested.
14. At any given temperature and voltage condition, t_{CHZ} max is less than t_{CLZ} min, and t_{OHZ} max is less than t_{OLZ} min, for any device.

Write Cycle (1) (WE# CLOCK, OE#="H" while writing)



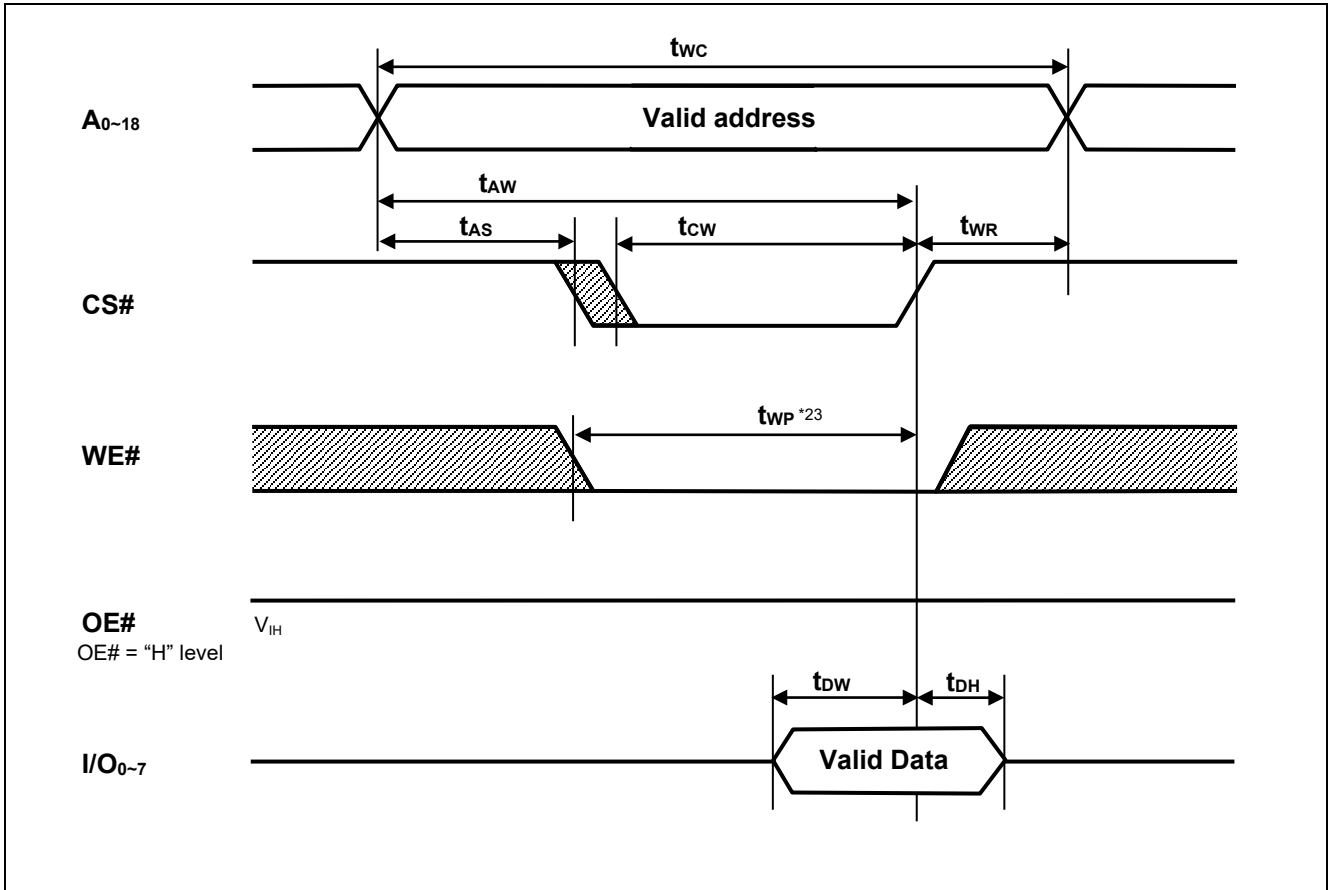
- Note 15. t_{wp} is the interval between write start and write end.
 A write starts when both of CS# and WE# become active.
 A write is performed during the overlap of a low CS# and a low WE#.
 A write ends when any of CS# or WE# becomes inactive.
16. t_{ohz} and t_{whz} are defined as the time when the I/O pins enter a high-impedance state and are not referred to the I/O levels.
17. This parameter is sampled and not 100% tested.
18. During this period, I/O pins are in the output state so input signals must not be applied to the I/O pins.

Write Cycle (2) (WE# CLOCK, OE# Low Fixed)



- Note 19. t_{WP} is the interval between write start and write end.
 A write starts when both of CS# and WE# become active.
 A write is performed during the overlap of a low CS# and a low WE#.
 A write ends when any of CS# or WE# becomes inactive.
20. t_{WHZ} is defined as the time when the I/O pins enter a high-impedance state and are not referred to the I/O levels.
21. This parameter is sampled and not 100% tested.
22. During this period, I/O pins are in the output state so input signals must not be applied to the I/O pins.

Write Cycle (3) (CS# CLOCK)



Note 23. t_{WP} is the interval between write start and write end.
 A write starts when both of CS# and WE# become active.
 A write is performed during the overlap of a low CS# and a low WE#.
 A write ends when any of CS# or WE# becomes inactive.

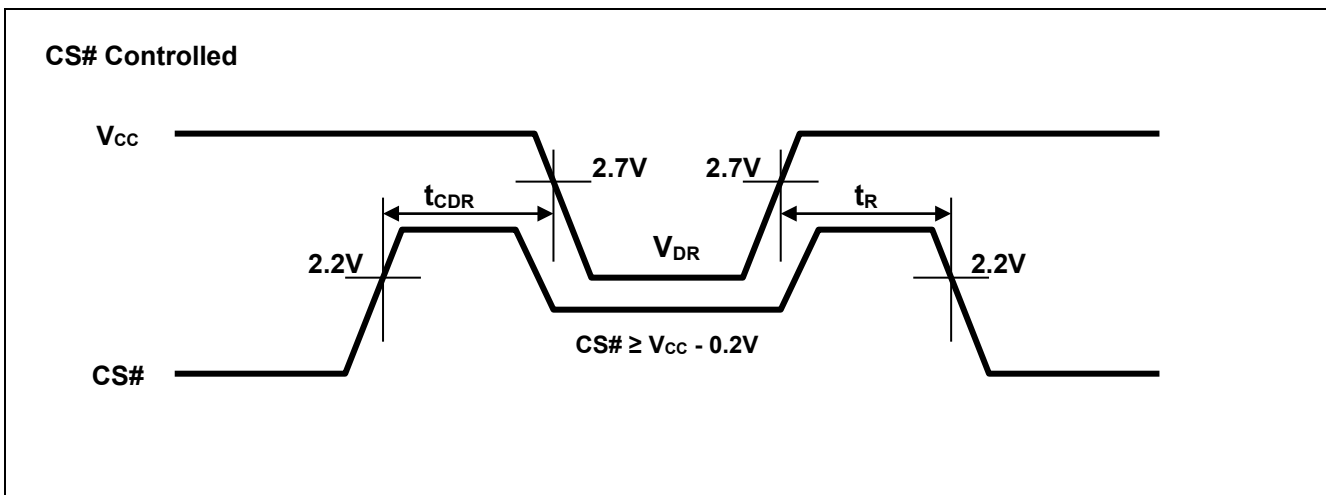
Low V_{CC} Data Retention Characteristics

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test conditions ^{*25}	
V _{CC} for data retention	V _{DR}	1.5	—	—	V	V _{in} ≥ 0V, CS# ≥ V _{CC} -0.2V	
Data retention current	I _{CCDR}	—	0.3 ^{*24}	2	μA	~+25°C	V _{CC} =3.0V, V _{in} ≥ 0V, CS# ≥ V _{CC} -0.2V
		—	—	3	μA	~+40°C	
		—	—	5	μA	~+70°C	
		—	—	7	μA	~+85°C	
Chip deselect time to data retention	t _{CDR}	0	—	—	ns	See retention waveform.	
Operation recovery time	t _R	5	—	—	ms		

Note 24. Typical parameter indicates the value for the center of distribution at 3.0V (T_a=25°C), and not 100% tested.

25. CS# controls address buffer, WE# buffer, OE# buffer, and I/O buffer. If CS# controls data retention mode, V_{in} levels (address, WE#, OE#, I/O) can be in the high-impedance state.

Low V_{CC} Data Retention Timing Waveforms (CS# controlled)



Revision History	RMLV0408E Series Data Sheet
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Rev.	Date	Description	
		Page	Summary
1.00	2014.2.27	—	First edition issued
2.00	2016.1.12	1	Changed section from “Part Name Information” to “Orderable part number information”
2.01	2020.2.20	Last page	Updated the Notice to the latest version
3.00	2021.8.18	1,4,10	Changed the typical value of I_{SB1} and I_{CCDR} from $0.4\mu A$ to $0.3\mu A$. Revised orderable part number information

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(Rev.1.0 Mar 2020)

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